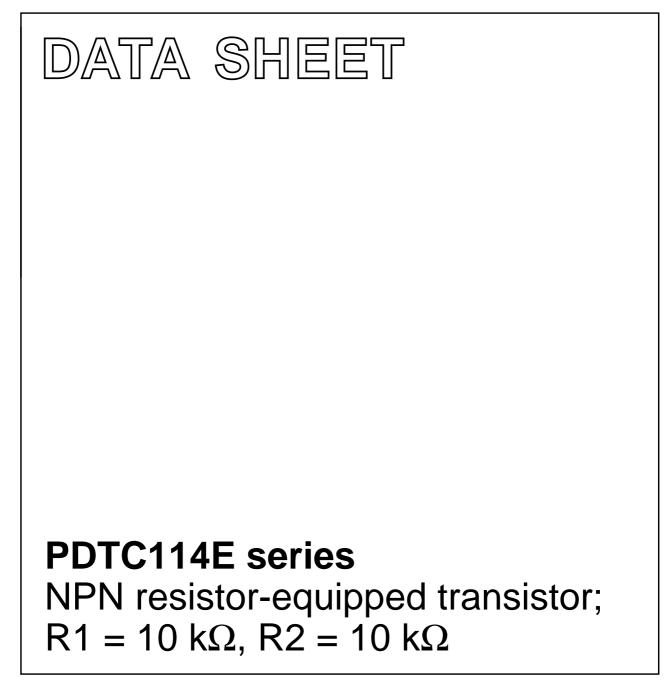
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 2003 Apr 10 2004 Aug 05



### **PDTC114E series**

#### FEATURES

- Built-in bias resistors
- Simplified circuit design
- Reduction of component count
- Reduced pick and place costs.

#### APPLICATIONS

- General purpose switching and amplification
- Inverter and interface circuits
- Circuit driver.

**PRODUCT OVERVIEW** 

#### QUICK REFERENCE DATA

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	-	50	V
lo	output current (DC)	-	100	mA
R1	bias resistor	10	_	kΩ
R2	bias resistor	10	_	kΩ

#### DESCRIPTION

NPN resistor-equipped transistor (see "Simplified outline, symbol and pinning" for package details).

TYPE NUMBER	PACKAGE		MARKING CODE	PNP COMPLEMENT	
	PHILIPS	EIAJ			
PDTC114EE	SOT416	SC-75	09	PDTA114EE	
PDTC114EEF	SOT490	SC-89	09	PDTA114EEF	
PDTC114EK	SOT346	SC-59	04	PDTA114EK	
PDTC114EM	SOT883	SC-101	DS	PDTA114EM	
PDTC114ES	SOT54 (TO-92)	SC-43	TC114E	PDTA114ES	
PDTC114ET	SOT23	_	*16 <sup>(1)</sup>	PDTA114ET	
PDTC114EU	SOT323	SC-70	*09(1)	PDTA114EU	

#### Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.
  - \* = W: Made in China.

## PDTC114E series

#### SIMPLIFIED OUTLINE, SYMBOL AND PINNING

	SIMPLIFIED OUTLINE AND SYMBOL		PINNING		
TYPE NUMBER			DESCRIPTION		
PDTC114ES		1 2	base collector		
		3	emitter		
PDTC114EE PDTC114EEF PDTC114EK PDTC114ET PDTC114EU	$\begin{array}{c} & & & & \\ & & & \\ & & & \\ & & & \\ 1 \\ & & & \\ Top view \end{array}$	1 2 3	base emitter collector		
PDTC114EM	2 1 bottom view MHC506	1 2 3	base emitter collector		

#### PDTC114E series

#### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V
VI	input voltage				
	positive		_	+40	V
	negative		_	-10	V
lo	output current (DC)		_	100	mA
I <sub>CM</sub>	peak collector current		-	100	mA
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	SOT54	note 1	_	500	mW
	SOT23	note 1	_	250	mW
	SOT346	note 1	_	250	mW
	SOT323	note 1	-	200	mW
	SOT416	note 1	-	150	mW
	SOT490	notes 1 and 2	_	250	mW
	SOT883	notes 2 and 3	_	250	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60 µm copper strip line.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	in free air		
	SOT54	note 1	250	K/W
	SOT23	note 1	500	K/W
	SOT346	note 1	500	K/W
	SOT323	note 1	625	K/W
	SOT416	note 1	833	K/W
	SOT490	notes 1 and 2	500	K/W
1	SOT883	notes 2 and 3	500	K/W

#### Notes

- 1. Refer to standard mounting conditions.
- 2. Reflow soldering is the only recommended soldering method.
- 3. Refer to SOT883 standard mounting conditions; FR4 with 60  $\mu$ m copper strip line.

## PDTC114E series

#### CHARACTERISTICS

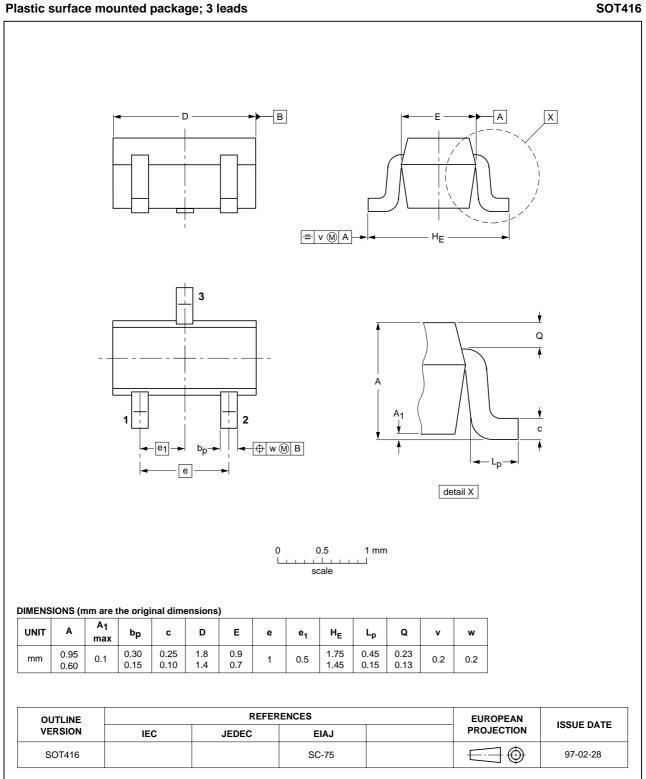
 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = 50 \text{ V}; \text{ I}_{E} = 0$	-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0$	-	-	1	μA
		$V_{CE} = 30 \text{ V}; \text{ I}_{B} = 0; \text{ T}_{j} = 150 ^{\circ}\text{C}$	-	-	50	μA
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0$	-	-	400	μA
h <sub>FE</sub>	DC current gain	$V_{CE} = 5 V; I_C = 5 mA$	30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	-	-	150	mV
V <sub>i(off)</sub>	input-off voltage	$I_{C} = 100 \ \mu A; V_{CE} = 5 \ V$	-	1.1	0.8	V
V <sub>i(on)</sub>	input-on voltage	$I_{C} = 10 \text{ mA}; V_{CE} = 0.3 \text{ V}$	2.5	1.8	-	V
R1	input resistor		7	10	13	kΩ
R2 R1	resistor ratio		0.8	1	1.2	
C <sub>c</sub>	collector capacitance	$I_{E} = i_{e} = 0; V_{CB} = 10 V; f = 1 MHz$		-	2.5	pF

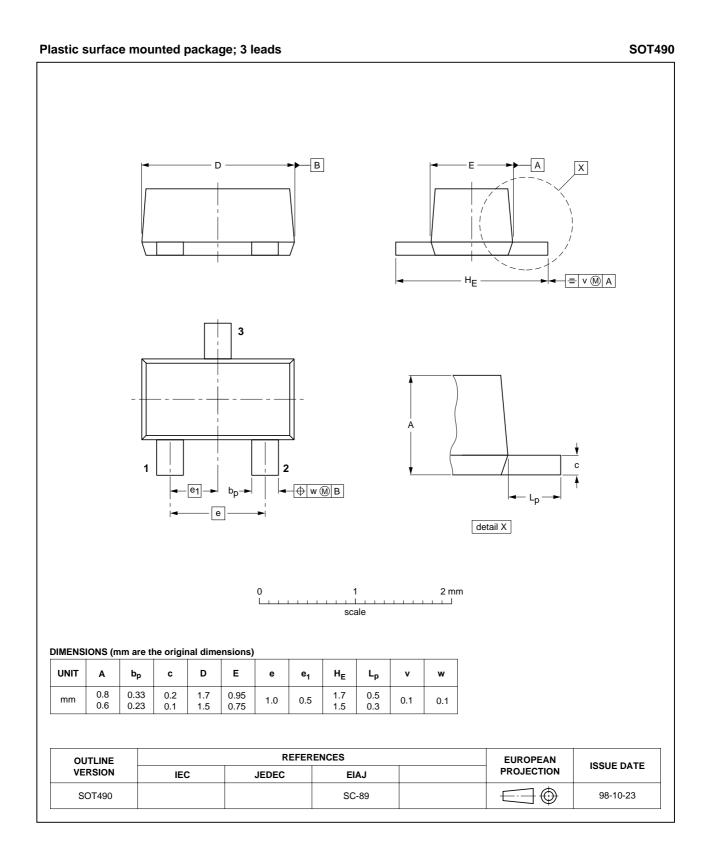
### NPN resistor-equipped transistor; $R1 = 10 \text{ k}\Omega$ , $R2 = 10 \text{ k}\Omega$

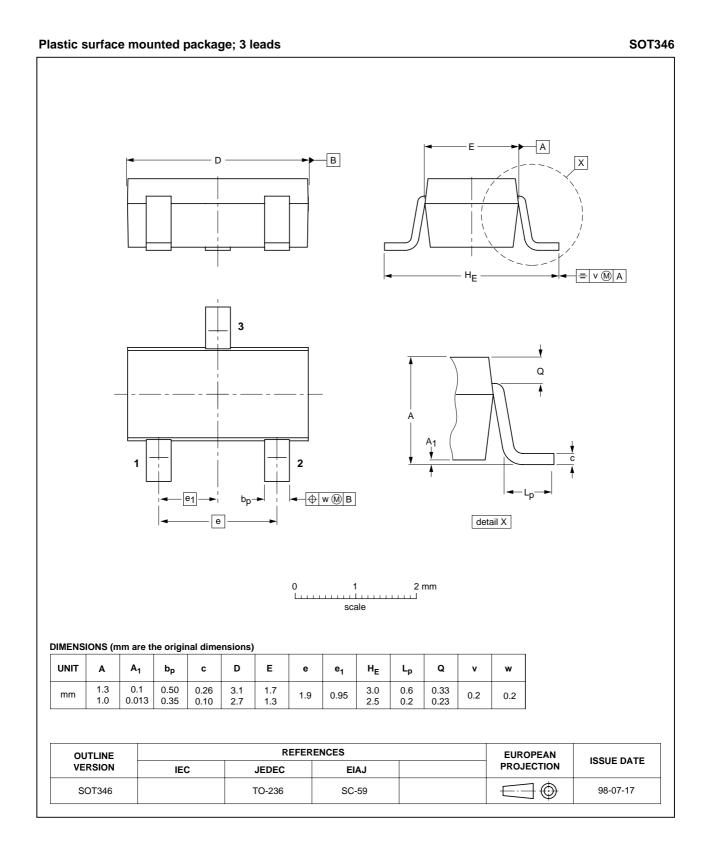
## PDTC114E series

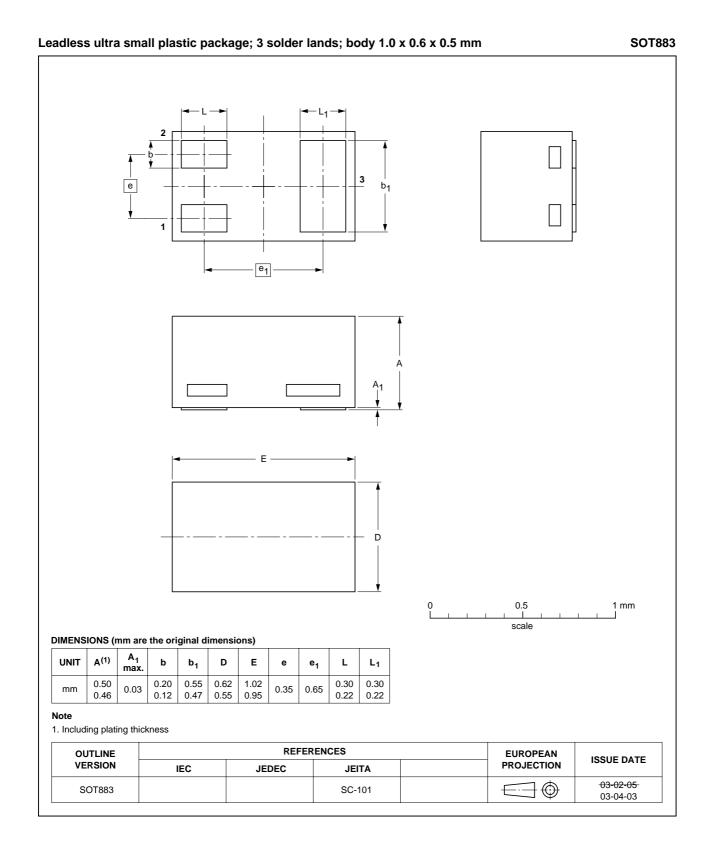
#### PACKAGE OUTLINES

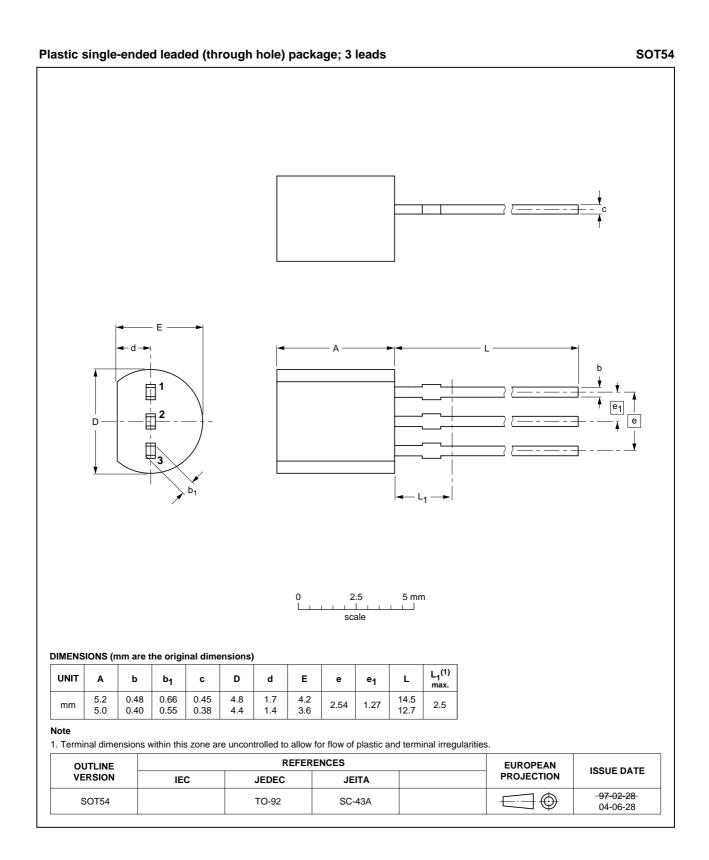


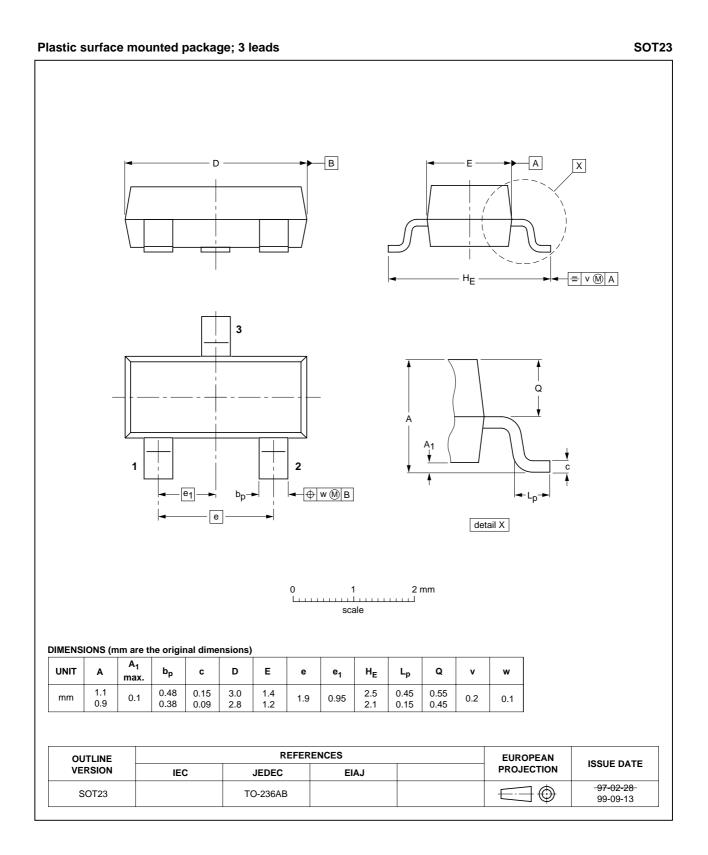
**SOT416** 

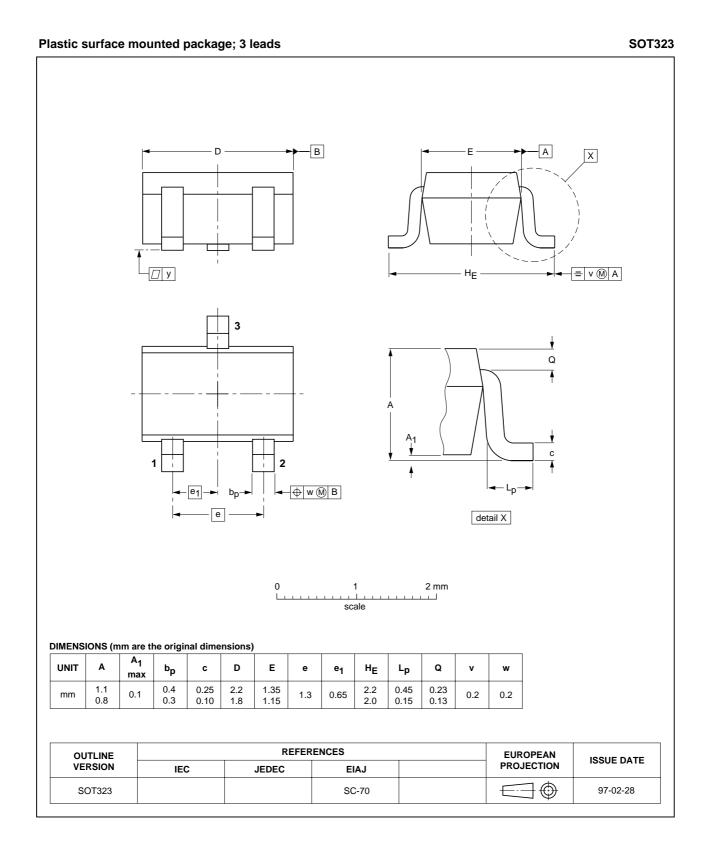












#### PDTC114E series

#### DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### DEFINITIONS

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Printed in The Netherlands

R75/10/pp14

Date of release: 2004 Aug 05

Document order number: 9397 750 13663

SCA76

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